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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/880,975	06/13/2001	Thomas J. Sonderman	2000.045300	5882

23720 7590 05/22/2003

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EXAMINER

KIELIN, ERIK J

ART UNIT	PAPER NUMBER
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2813

DATE MAILED: 05/22/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary

Application No.

09/880,975

Applicant(s)

SONDERMAN ET AL.

Examiner

Erik Kielin

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 25 March 2003.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1,7-12 and 22 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1,7-12 and 22 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 25 March 2003 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
- Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- 11) ☐ The proposed drawing correction filed on _____ is: a) ☐ approved b) ☐ disapproved by the Examiner.
- If approved, corrected drawings are required in reply to this Office action.
- 12) ☐ The oath or declaration is objected to by the Examiner.

Priority under 35 U.S.C. §§ 119 and 120

- 13) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- * See the attached detailed Office action for a list of the certified copies not received.
- 14) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).
- a) ☐ The translation of the foreign language provisional application has been received.
- 15) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

Attachment(s)

- 1) ☐ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☐ Information Disclosure Statement(s) (PTO-1449) Paper No(s) _____
- 4) ☐ Interview Summary (PTO-413) Paper No(s). _____
- 5) ☐ Notice of Informal Patent Application (PTO-152)
- 6) ☐ Other: _____

DETAILED ACTION

Drawings

The corrected or substitute drawings were received on 25 March 2003. These drawings are acceptable.

Claim Rejections - 35 USC § 103

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

2. Claims 1, 7-12, and 22 are rejected under 35 U.S.C. 103(a) as being unpatentable over US 6,428,673 B1 (**Ritzdorf** et al.) in view of **Wolf**, et al. Silicon Processing for the VLSI Era, Vol. 1-Process Technology, 2nd ed., Lattice Press: Sunset Beach CA, 2000, pp. 799-800, and US 6,298,470 B1 (**Breiner** et al.).

Regarding claims 1 and 22, **Ritzdorf** discloses a method for controlling a thickness of an electroplated copper layer including damascene layers (col. 3, lines 10-21) using feedback from metrology comprising,

forming a first copper layer;

measuring an actual thickness of the copper layer;

comparing the actual thickness to a desired thickness; and

varying at least one parameter used to form the first copper layer in response to the actual thickness differing from the desired thickness. (See Abstract; col. 3, line 64 to col. 4, line 15; col. 4, lines 37-65; col. 5, lines 2-5; col. 7, lines 36-45; col. 8, lines 49-53.)

Ritzdorf does not describe the damascene process disclosed therein.

The basic textbook of **Wolf** discloses the basic copper damascene process known to one of ordinary skill also includes the formation of the dielectric with the opening, or in Applicant's claim language,

forming a first dielectric layer above a first structure layer (called "IMO deposition" in

Wolf, Fig. 15-60, wherein IMO stands for intermetal oxide);

forming a first opening in the first dielectric layer (called "trench patterning and "via patterning");

forming a first copper layer above the first dielectric layer and in the first opening.

(See **Wolf**, pp. 799-800, especially Fig. 15-60.)

It would have been obvious for one of ordinary skill in the art, at the time of the invention to form the damascene structure in **Ritzdorf**, according to steps indicated in **Wolf**, because **Ritzdorf** says a damascene structure is used and **Wolf** teaches the notoriously well known steps for forming the damascene structure.

Then the only difference is that **Ritzdorf** does not teach the limitation that measuring the actual thickness of the copper layer comprises, "averaging a plurality of thicknesses from a plurality of locations" on said first copper layer.

Breiner teaches a method of process control during semiconductor fabrication by feedback from metrology tools (col. 3, lines 25-67) citing specific examples, wherein the data,

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including the thickness of deposited metal layers (col. 4, lines 20-25), is data that may be used to provide process control feedback. It is further stated therein that,

“The wafer data may be collected and tracked on a per wafer basis, per lot basis, per process run basis or combinations thereof. Further, the data may include **multiple measurements for each data point, mean values, median values**, range of values, standard deviations, **wafer maps** of the collected data, etc.” (col. 4, lines 60-65).

It would have been obvious for one of ordinary skill in the art, at the time of the invention to “average a plurality of thicknesses from a plurality of locations” in determining the uniformity in **Ritzdorf**, in order to make the “wafer map” of thickness which shows the thickness globally, and provides a visual mapping of the uniformity, as taught in **Breiner**.

Regarding claim 7, it is seen to be inherent that the actual thickness is measured at a plurality of locations, because **Ritzdorf** indicates that the uniformity is determined thereby requiring the thickness determination at several points. (See MPEP 2112.)

Regarding claims 8 and 9, the prior art of **Ritzdorf**, as explained above, discloses each of the claimed features except for indicating that the measuring of the thickness at a plurality of locations includes determining the average or median of the actual measured thickness.

It would have been obvious for one of ordinary skill in the art, at the time of the invention to use the average or median (called “mean” in **Breiner**) of the plurality of points measured in **Ritzdorf** as taught in **Breiner** as a matter of design choice because the average or median values would provide better a more precise measure of the thickness over the entire wafer than would a collection of un-analyzed thickness measurements.

Regarding claims 10-12, the prior art of **Ritzdorf**, as explained above, discloses each of the claimed features except for indicating that the measuring of the thickness at a plurality of

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locations, inherently disclosed in **Ritzdorf**, includes comparing the desired thickness to each of the plurality of measured thicknesses (claim 10) or comparing the desired thickness to the average (claim 11) or median values (claim 12) of the thickness.

As noted above, **Breiner** teaches that the any of the above-highlighted data (each of the plurality of thicknesses, the average thickness, or the median thickness) provide feedback for process control. Feedback necessarily requires comparison of measured data to some desired value, otherwise there would exist no direction in which to modify the process to move in the direction of the desired value, and consequently no control could be provided. Moreover, **Breiner** provides examples of process control based upon feedback of measured thickness (col. 6, lines 15-32 and col. 7, lines 15-38).

It would have been obvious for one of ordinary skill in the art, at the time of the invention to compare the measured data (each of the plurality of thicknesses, the average thickness, or the median thickness) as taught by **Breiner** in the method of **Ritzdorf**, because **Ritzdorf** indicates that thickness and uniformity are data used to modify the process of depositing copper and because **Breiner** teaches that any of the measured data (each of the plurality of thicknesses, the average thickness, or the median thickness) may be used to provide feedback (i.e. comparison to a desired value) for process control.

Response to Arguments

3. Applicant's arguments with respect to all active claims have been considered but are moot in view of the new ground(s) of rejection.

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Conclusion

This action is made non-final to allow Applicant to respond to the new grounds of rejection.


US Patent Application 2002/0083401 (**Breiner et al.**) is a continuation application of that issuing as the **Breiner** patent applied above.

US 5,312,532 (**Andricacos et al.**) teaches measuring the thickness at a plurality of locations of electroplated copper and averaging the data and determining a standard deviation. (See Fig. 6a.)

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Erik Kielin whose telephone number is 703-306-5980. The examiner can normally be reached on 9:00 - 19:30 on Monday through Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead, Jr., can be reached at 703-308-4940. The fax phone numbers for the organization where this application or proceeding is assigned are 703-872-9318 for regular communications and 703-872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.


Erik Kielin
May 18, 2003